

TOSHIBA Photocoupler Photorelay

TLP176GA

PBX

Telecommunication

Modem·FAX Cards, Modems In PC

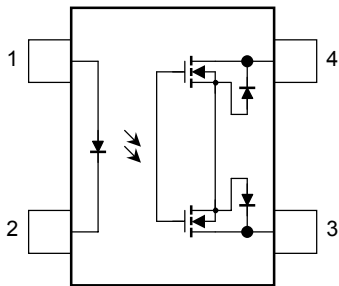
Measurement Instrumentation

The TOSHIBA TLP176GA consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a SOP, which is suitable for surface mount assembly.

The TLP176GA is suitable for the modem applications which require space savings.

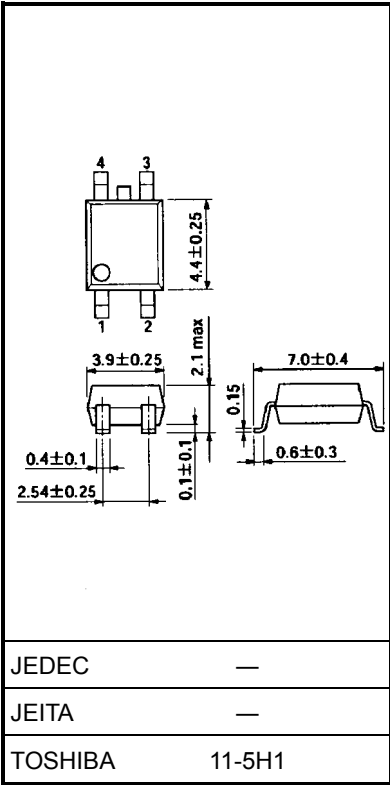
- 4 pin SOP (2.54SOP4): 2.1 mm high, 2.54 mm pitch
- 1-form-A
- Peak off-state voltage: 400 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 120 mA (max)
- On-state resistance: 35 Ω (max)
- Isolation voltage: 1500 Vrms (min)

Pin Configuration (top view)



- 1: ANODE
- 2: CATHODE
- 3: DRAIN
- 4: DRAIN

Unit: mm



Weight: 0.1 g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Forward current derating (Ta ≥ 25°C)	$\Delta I_F/^\circ\text{C}$	-0.5	mA/°C
	Peak forward current (100 μs pulse, 100 pps)	I_{FP}	1	A
	Reverse voltage	V_R	5	V
	Junction temperature	T_j	125	°C
Detector	Off-state output terminal voltage	V_{OFF}	400	V
	On-state current	I_{ON}	120	mA
	On-state current derating (Ta ≥ 25°C)	$\Delta I_{ON}/^\circ\text{C}$	-1.2	mA/°C
	Junction temperature	T_j	125	°C
Operating temperature range		T_{opr}	-40 to 85	°C
Storage temperature range		T_{stg}	-55 to 125	°C
Lead soldering temperature (10 s)		T_{sol}	260	°C
Isolation voltage (AC, 1 min, R.H. ≤ 60%) (Note 1)		BV_S	1500	Vrms

Note 1: Device considered a two-terminal device: LED side pins shorted together, and DETECTOR side pins shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Typ.	Max	Unit
Supply voltage	V_{DD}	—	—	320	V
Forward current	I_F	5	7.5	25	mA
On-state current	I_{ON}	—	—	120	mA
Operating temperature	T_{opr}	-20	—	65	°C

Individual Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Off-state current	I_{OFF}	$V_{OFF} = 400 \text{ V}$	—	—	1	μA
	Capacitance	C_{OFF}	$V = 0, f = 1 \text{ MHz}$	—	70	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current	I_{FT}	$I_{ON} = 120 \text{ mA}$	—	1	3	mA
Return LED current	I_{FC}	$I_{OFF} = 100 \text{ μA}$	0.1	—	—	mA
On-state resistance	R_{ON}	$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$	—	17	35	Ω

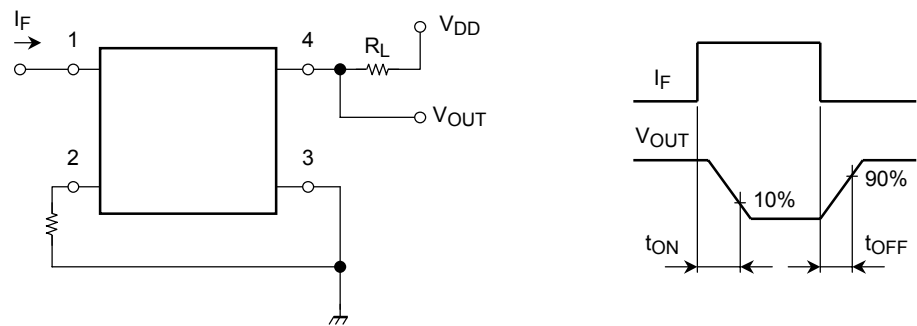
Isolation Characteristics (Ta = 25°C)

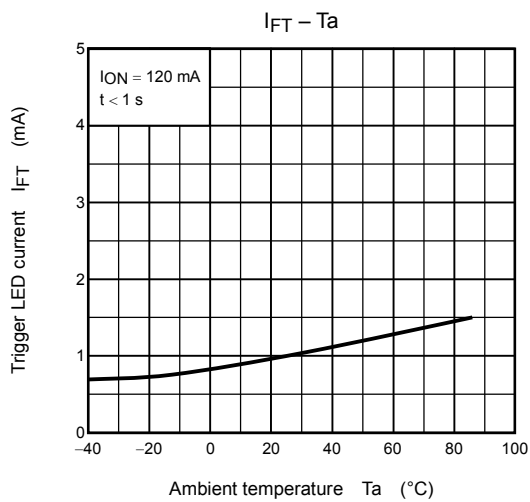
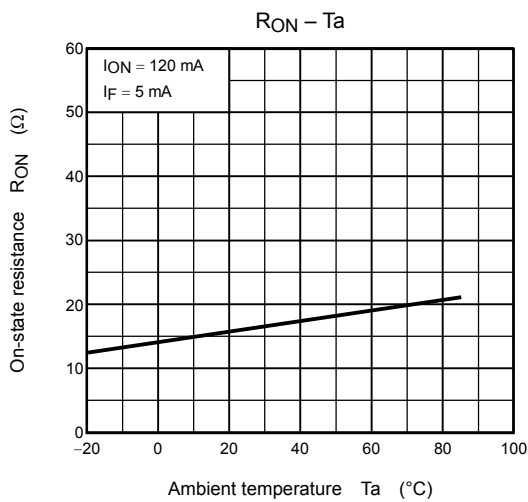
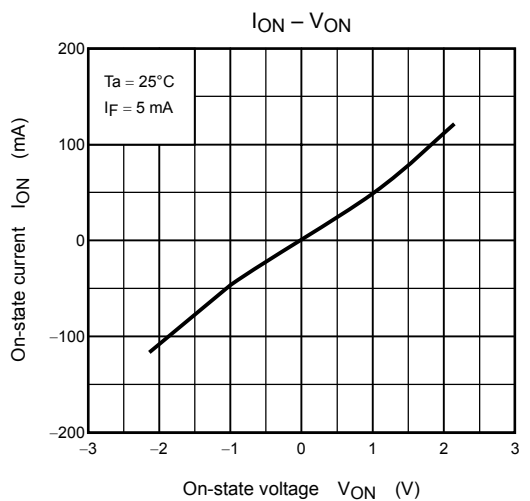
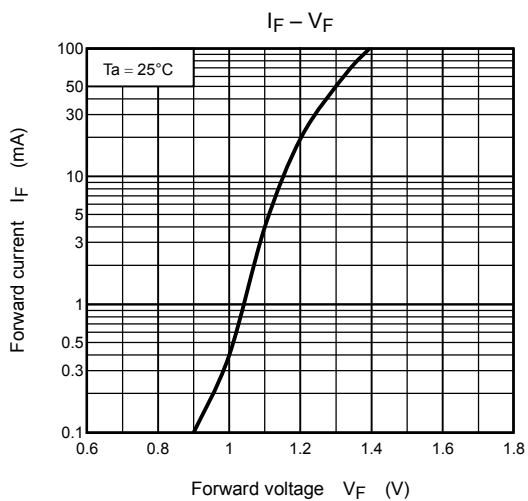
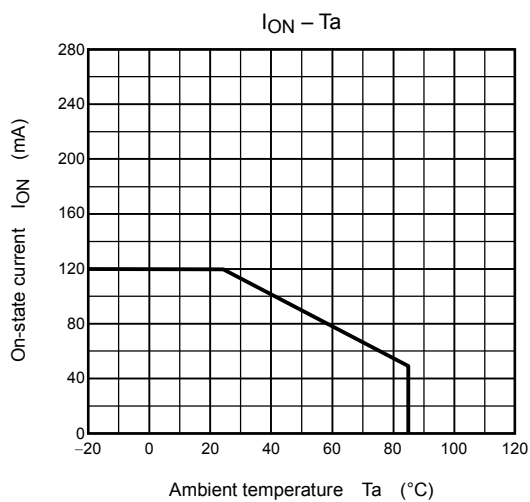
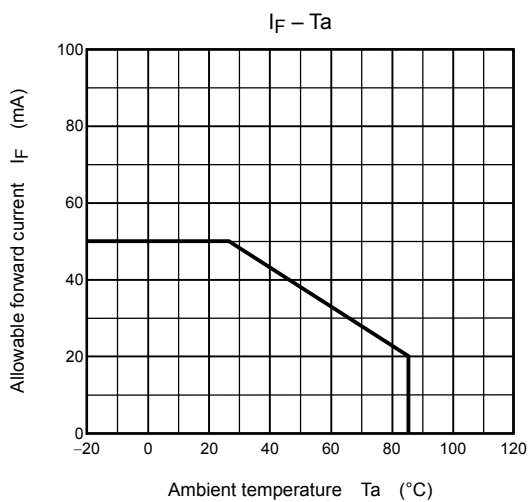
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output	CS	VS = 0, f = 1 MHz	—	0.8	—	pF
Isolation resistance	RS	VS = 500 V, R.H. ≤ 60%	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BVS	AC, 1 min	1500	—	—	Vrms
		AC, 1 s, in oil	—	3000	—	
		DC, 1 min, in oil	—	3000	—	Vdc

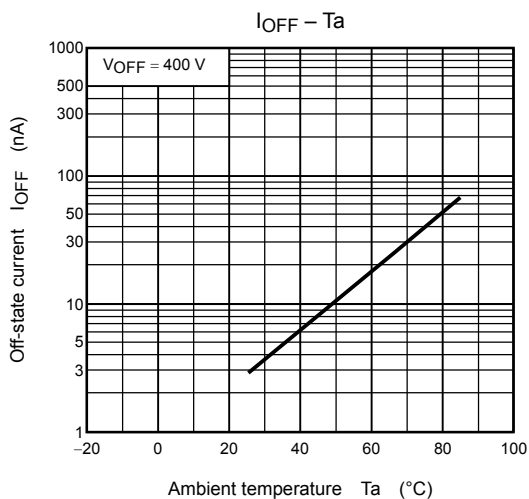
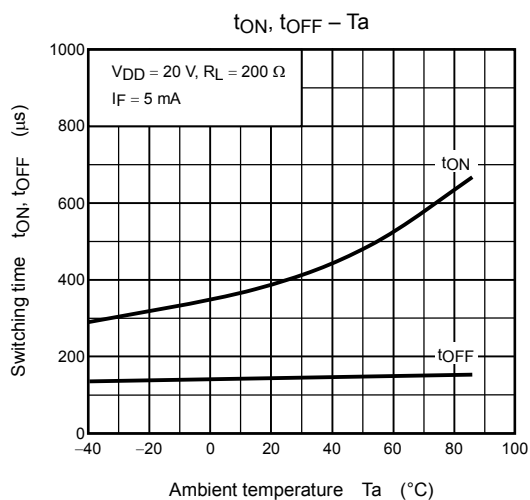
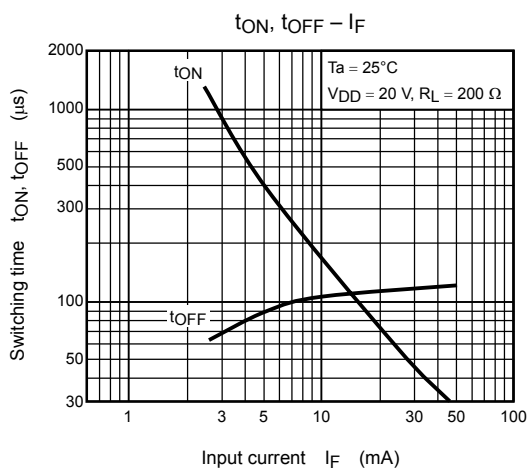
Switching Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Turn-on time	tON	RL = 200 Ω (Note 2)	—	0.3	1	ms
Turn-off time	tOFF	VDD = 20 V, IF = 5 mA	—	0.1	1	ms

Note 2: Switching time test circuit







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000707EBC

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